



<b>IN THE UNITED STATES PATENT AND TRADEMARK OFFICE</b>	Application No.	10/024,475 ✓
	Filing Date	December 12, 2001
	First Named Inventor	Chan-ho PARK
	Group Art Unit	2811
	Examiner Name	Im, Junghwa M.
	Attorney Docket No.	1751-294
Title of the Invention: <b>HIGH VOLTAGE SEMICONDUCTOR DEVICE HAVING HIGH BREAKDOWN VOLTAGE AND METHOD OF FABRICATING THE SAME</b>		

#8/A  
And  
J. McNeill  
3/6/03

**AMENDMENT UNDER 37 C.F.R. § 1.111**

Assistant Commissioner for Patents  
Washington, D.C. 20231

Dear Sir:

In response to the Office Action mailed December 4, 2002, please enter the amendments contained on the following page, which are summarized below.

**IN THE CLAIMS:**

Please amend claim 1.

Please cancel claim 2 without prejudice or disclaimer.

A marked-up copy of the original text of the amended claim is attached to this amendment. Material inserted is indicated by underlining and material deleted is indicated by brackets.

RECEIVED  
MAR - 5 2003  
TECHNOLOGY CENTER 2800